

Description

The SI2309A uses advanced trench technology and design to provide excellent $R_{\text{DS}(\text{ON})}$ with low gate charge .This device is well suited for use as a load switch or in PWM applications.



General Features

 V_{DS} =-60V,I $_{D}$ =-1.6A

 $R_{DS(ON)}$ <160m Ω @ V_{GS} =-10V

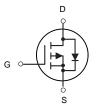
 $R_{DS(ON)}$ <200m Ω @ V_{GS} =-4.5V



Application

Load switch

PWM application



P-Channel MOSFET

Package Marking and Ordering Information

| Product ID | Pack | Marking | Qty(PCS) |
|------------|--------|---------|----------|
| SI2309A | SOT-23 | 2309 | 3000 |

Absolute Maximum Ratings (TA=25 ℃ unless otherwise noted)

| Symbol | Parameter | Limit | Unit |
|-----------------|--|------------|------|
| V _{DS} | Drain-Source Voltage | -60 | V |
| Vgs | Gate-Source Voltage | ±20 | V |
| I _D | Drain Current-Continuous | -1.6 | А |
| Ірм | Drain Current-Pulsed (Note 1) | -8 | А |
| P _D | Maximum Power Dissipation | 1.5 | W |
| Тл,Твтв | Operating Junction and Storage Temperature Range | -55 To 150 | °C |
| Reja | Thermal Resistance,Junction-to-Ambient (Note 2) | 83.3 | °C/W |



Electrical Characteristics (T_C=25 ℃ unless otherwise noted)

| Parameter Symbol Condition | | Min | Тур | Max | Unit | |
|------------------------------------|---------------------|--|------|-------|------|----|
| Off Characteristics | | | • | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =-250μA -60 | | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-60V,V _{GS} =0V | - | - | -1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | • | | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} ,I _D =-250μA | -1.4 | -2.0 | -2.6 | V |
| Dunin Course On Ctata Desistance | R _{DS(ON)} | V _{GS} =-10V, I _D =-1.5A | - | 140 | 160 | mΩ |
| Drain-Source On-State Resistance | | V _{GS} =-4.5V, I _D =-1.5A | - | 160 | 200 | mΩ |
| Forward Transconductance | g Fs | V _{DS} =-5V,I _D =-1.5A | - | 3 | - | S |
| Dynamic Characteristics (Note4) | | | | | | |
| Input Capacitance | C _{lss} | \/ - 20\/\/ -0\/ | - | 444.2 | - | PF |
| Output Capacitance | C _{oss} | V_{DS} =-30V, V_{GS} =0V, F=1.0MHz | - | 19.6 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | r-1.0WHZ | - | 17.9 | - | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 40 | - | nS |
| Turn-on Rise Time | t _r | V_{DD} =-30V, I_{D} =-1.5A, | - | 35 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =-10 V , R_G =3 Ω | - | 15 | - | nS |
| Turn-Off Fall Time | t _f | | - | 10 | - | nS |
| Total Gate Charge | Qg | V - 20 I - 4 FA | - | 11.3 | - | nC |
| Gate-Source Charge | Q _{gs} | V _{DS} =-30,I _D =-1.5A, V _{GS} =-10V | - | 2.7 | - | nC |
| Gate-Drain Charge | Q _{gd} | VGS10V | - | 1.6 | - | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =-1.5A | - | | -1.2 | V |
| Diode Forward Current (Note 2) | Is | | - | - | -1.6 | А |
| Reverse Recovery Time | t _{rr} | T _J = 25°C, I _F =- 1.5A | - | 25 | | nS |
| Reverse Recovery Charge | Qrr | $di/dt = -100A/\mu s^{(Note3)}$ | - | 31 | | nC |

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical and Thermal Characteristics (Curves)

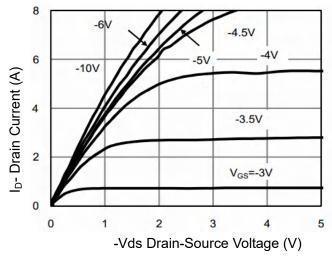


Figure 1 Output Characteristics

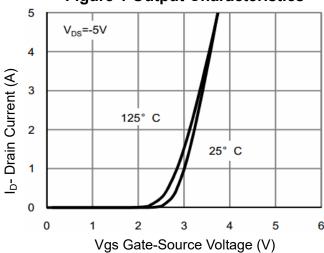
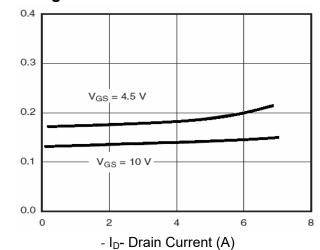


Figure 2 Transfer Characteristics



Rdson On-Resistance(()

Figure 3 Rdson- Drain Current

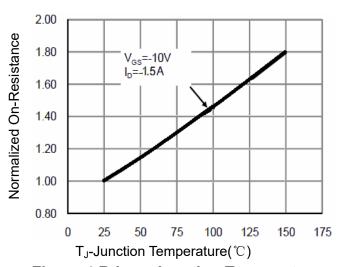
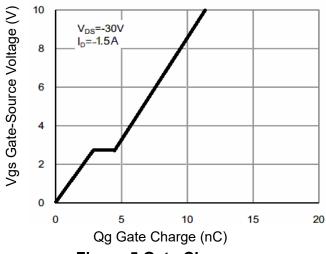


Figure 4 Rdson-Junction Temperature



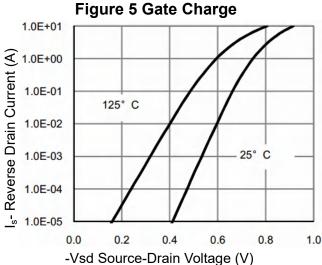


Figure 6 Source- Drain Diode Forward



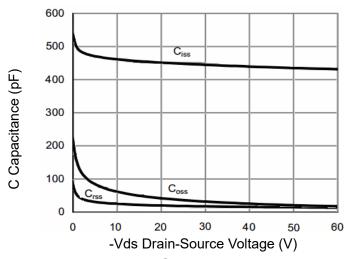


Figure 7 Capacitance vs Vds

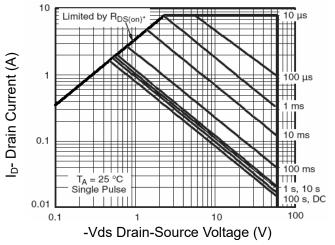


Figure 8 Safe Operation Area

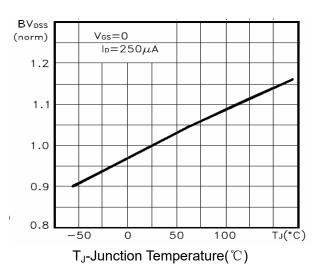


Figure 9 BV_{DSS} vs Junction Temperature

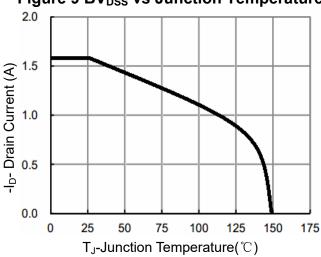
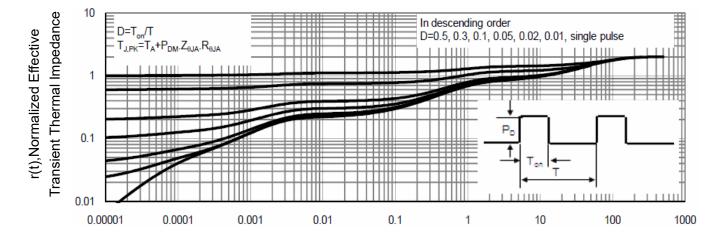


Figure 10 ID Current De-rating



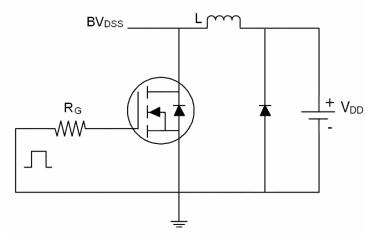
Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

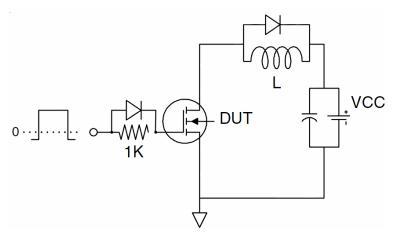


Test Circuit

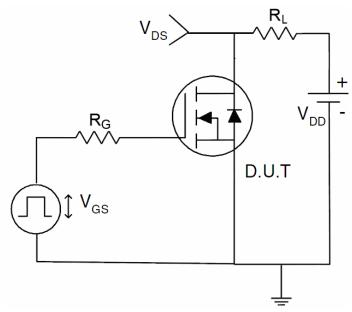
1) E_{AS} test Circuit



2) Gate charge test Circuit

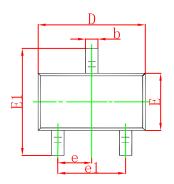


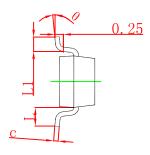
3) Switch Time Test Circuit

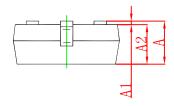




SOT-23 Package Outline Dimensions

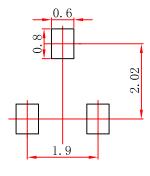






| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------|----------------------|-------|--|
| | Min | Max | Min | Max | |
| Α | 0.900 | 1.150 | 0.035 | 0.045 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| С | 0.080 | 0.150 | 0.003 | 0.006 | |
| D | 2.800 | 3.000 | 0.110 | 0.118 | |
| E | 1.200 | 1.400 | 0.047 | 0.055 | |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 | |
| е | 0.950 TYP | | 0.037 TYP | | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.550 REF | | 0.022 REF | | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 | |
| θ | 0° | 8° | 0° | 8° | |

SOT-23 Suggested Pad Layout



- Note: 1.Controlling dimension: in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.



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